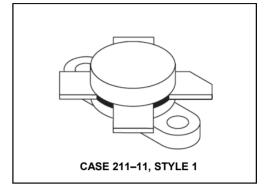


Rev. V1

Designed primarily for applications as a high–power linear amplifier from 2.0 **Product Image** to 30 MHz.

- Specified 28 V, 30 MHz characteristics —
 Output power = 150 W (PEP)
 Minimum gain = 10 dB
 Efficiency = 40%
- Intermodulation distortion @ 150 W (PEP) —IMD = -30 dB (min.)
- 100% tested for load mismatch at all phase angles with 30:1 VSWR



MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V _{CEO}	40	Vdc
Collector-Base Voltage	V _{CBO}	85	Vdc
Emitter-Base Voltage	V _{EBO}	3.0	Vdc
Collector Current — Continuous	Ic	20	Adc
Withstanding Current — 10 s	_	30	Adc
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D	290 1.66	Watts W/°C
Storage Temperature Range	T _{stg}	-65 to +150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	R _{0JC}	0.6	°C/W

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					•
Collector–Emitter Breakdown Voltage (I _C = 200 mAdc, I _B = 0)	V _{(BR)CEO}	35	_	_	Vdc
Collector–Emitter Breakdown Voltage (I _C = 100 mAdc, V _{BE} = 0)	V _{(BR)CES}	85	_	_	Vdc
Collector–Base Breakdown Voltage (I _C = 100 mAdc, I _E = 0)	V _{(BR)CBO}	85	_	_	Vdc
Emitter-Base Breakdown Voltage (I _E = 10 mAdc, I _C = 0)	V _{(BR)EBO}	3.0	_	_	Vdc
Collector Cutoff Current (V _{CE} = 28 Vdc, V _{BE} = 0, T _C = 25°C)	I _{CES}	_	_	20	mAdc

(continued)

1

MRF422



The RF Line NPN Silicon Power Transistor 150W(PEP), 30MHz, 28V

Rev. V1

ELECTRICAL CHARACTERISTICS — continued (T_C = 25°C unless otherwise noted.)

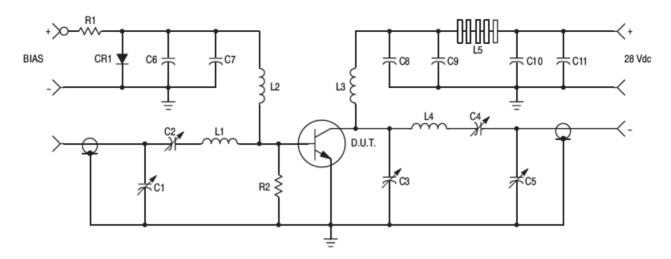
Characteristic	Symbol	Min	Тур	Max	Unit
ON CHARACTERISTICS	•			,	
DC Current Gain (I _C = 5.0 Adc, V _{CE} = 5.0 Vdc)	h _{FE}	15	30	120	_
DYNAMIC CHARACTERISTICS					
Output Capacitance (V _{CB} = 28 Vdc, I _E = 0, f = 1.0 MHz)	C _{ob}	_	420	_	pF
FUNCTIONAL TESTS					
Common–Emitter Amplifier Power Gain (V _{CC} = 28 Vdc, P _{out} = 150 W (PEP), I _{C(max)} = 6.7 Adc, I _{CQ} = 150 mAdc, f = 30, 30.001 MHz)	GPE	10	13	_	dB
Collector Efficiency (V _{CC} = 28 Vdc, P _{out} = 150 W (PEP), I _{C(max)} = 6.7 Adc, I _{CQ} = 150 mAdc, f = 30, 30.001 MHz)	η	_	45	_	%
Intermodulation Distortion (1) (V_{CE} = 28 Vdc, P_{out} = 150 W (PEP), I_{C} = 6.7 Adc, I_{CQ} = 150 mAdc, f = 30, 30.001 MHz)	IMD	_	-33	-30	dB
Output Power (V _{CE} = 28 Vdc, f = 30 MHz)	P _{out}	150	_	_	Watts (PEP)

NOTE:

^{1.} To Mil-Std-1311 Version A, Test Method 2204, Two Tone, Reference each Tone.



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C1, C2, C3, C5 — 170–680 pF, ARCO 469 C4 — 80–480 pF, ARCO 466 C6, C8, C11 — ERIE 0.1 µF, 100 V C7 — MALLORY 500 µF, 15 V Electrolytic C9 — UNDERWOOD 1000 pF, 350 V C10 — 10 µF, 50 V Electrolytic

R1 — 10 Ω , 25 Watt Wire Wound R2 — 10 Ω , 1.0 Watt Carbon

CR1 - 1N4997

L1 - 3 Turns, #16 Wire, 5/16" I.D., 5/16" Long

L2 - 10 μH Molded Choke

L3 — 12 Turns, #16 Enameled Wire, Close Wound, 1/4" Dia.

L4 - 5 Turns, 1/8" Copper Tubing

L5 - 10 Ferrite Beads - FERROXCUBE #56-590-65/3B

Figure 1. 30 MHz Test Circuit Schematic



Rev. V1

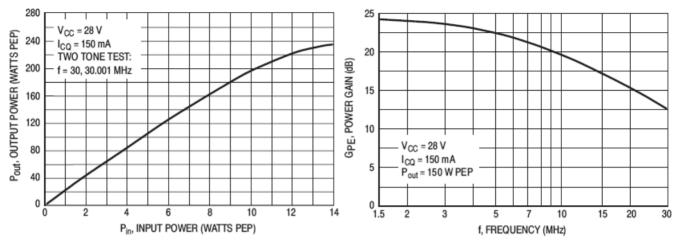


Figure 2. Output Power versus Input Power

Figure 3. Power Gain versus Frequency

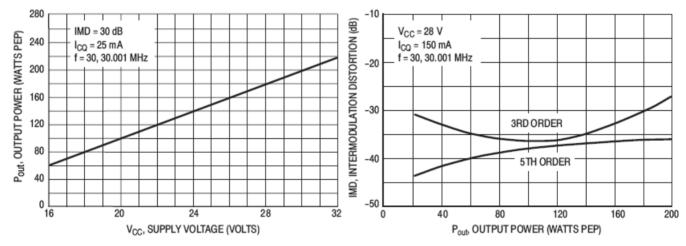


Figure 4. Linear Output Power versus Supply Voltage

Figure 5. Intermodulation Distortion versus Output Power



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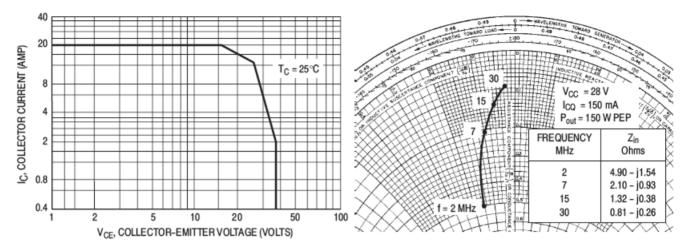


Figure 6. DC Safe Operating Area

Figure 7. Series Input Impedance



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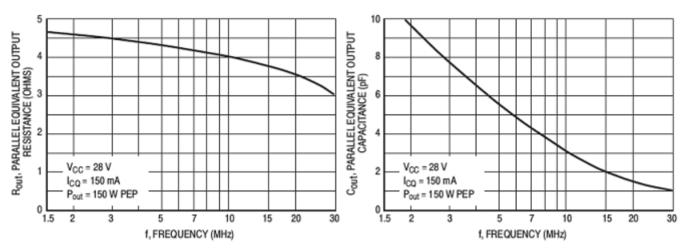
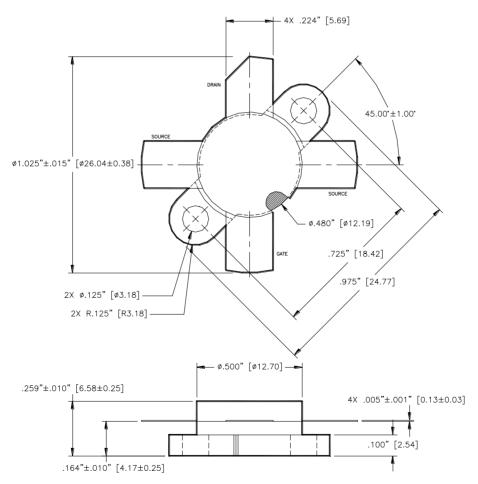


Figure 8. Output Resistance versus Frequency

Figure 9. Output Capacitance versus Frequency



Unless otherwise noted, tolerances are inches $\pm .005$ " [millimeters ± 0.13 mm]

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The RF Line NPN Silicon Power Transistor 150W(PEP), 30MHz, 28V

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